



DMNH4011SPSQ

40V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	Ι <sub>D</sub> T <sub>C</sub> = +25°C
40V	10mΩ @ V <sub>GS</sub> = 10V	80A

### **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine Management Systems
- DC-DC Converters
- Body Control Electronics

#### **Features and Benefits**

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- $\bullet \qquad \text{Low } Q_g \text{Minimizes Switching Loss}\\$
- Low R<sub>DS(ON)</sub> Minimizes On State Loss
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

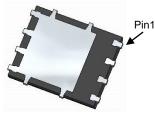
#### Mechanical Data

- Case: PowerDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)

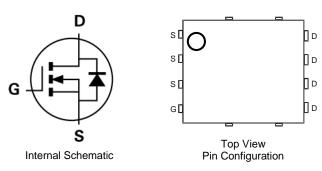


Top View

Notes:



Bottom View



## Ordering Information (Note 5)

Part Number	Case	Packaging
DMNH4011SPSQ-13	PowerDI5060-8	2,500 / Tape & Reel

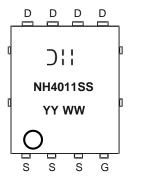
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

 See http://www.diodes.com/quality/lead\_tree.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product\_compliance\_definitions.html.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



)'| = Manufacturer's Marking
NH4011SS = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 17 = 2017)
WW = Week (01 to 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V <sub>DSS</sub>	40	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	13 10.8	A
Continuous Drain Current (Note 7) $V_{GS}$ = 10V	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$ $(Note 8)$	ID	80 57	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	90	A
Maximum Continuous Body Diode Forward Current (Note 6)		Is	80	A
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)		I <sub>SM</sub>	90	A
Avalanche Current, L = 1mH		I <sub>AS</sub>	18	A
Avalanche Energy, L = 1mH		E <sub>AS</sub>	170	mJ

#### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	PD	2.5	W
Thermal Resistance, Junction to Ambient (Note 6)		R <sub>0JA</sub>	60	°C/W
Total Power Dissipation (Note 7)	$T_{C} = +25^{\circ}C$	PD	150	W
Thermal Resistance, Junction to Case (Note 7)		R <sub>eJC</sub>	1	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

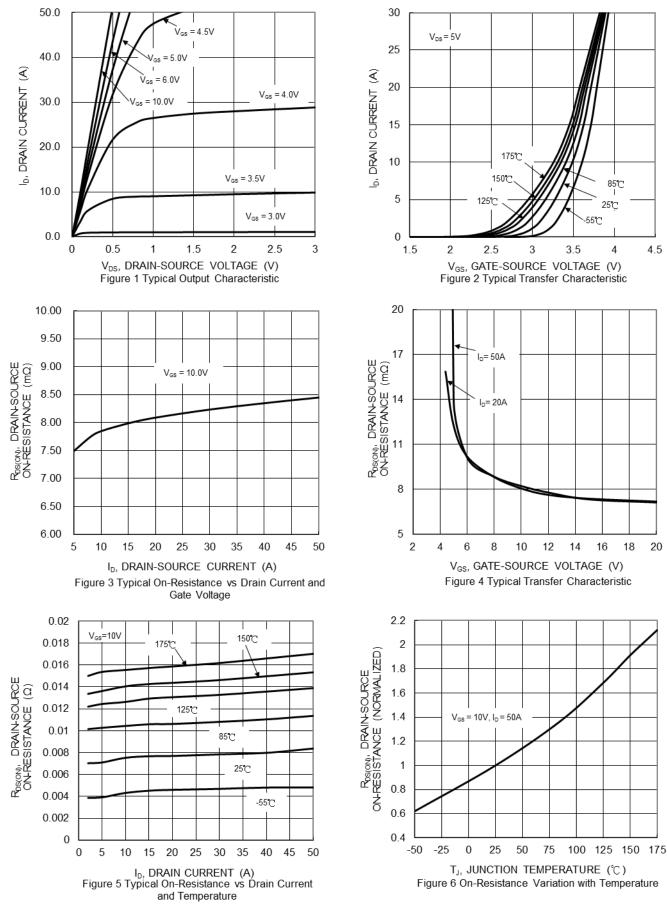
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	40	_	-	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	$V_{DS} = 40V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	2	—	4	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		8.5	10	mΩ	$V_{GS} = 10V, I_D = 50A$	
Diode Forward Voltage	V <sub>SD</sub>	_	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 50A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss		1405	—	pF	$V_{DS}$ = 20V, $V_{GS}$ = 0V, f = 1MHz	
Output Capacitance	Coss	_	247	_			
Reverse Transfer Capacitance	Crss	_	108	-			
Gate Resistance	Rg	_	2.2	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	25.5	_		$V_{DS} = 20V, V_{GS} = 10V, I_D = 50A$	
Gate-Source Charge	Q <sub>gs</sub>	_	4.6	_	nC		
Gate-Drain Charge	Q <sub>gd</sub>	_	6.9	_			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	4.6	_		$V_{DD} = 20V, V_{GS} = 10V,$ $I_D = 50A, R_G = 3.5\Omega$	
Turn-On Rise Time	t <sub>R</sub>	_	3.7	_			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	16	_	ns		
Turn-Off Fall Time	tF	_	5.1	_			
Body Diode Reverse Recovery Time	t <sub>RR</sub>		22.1	_	ns		
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	13.4		nC	I <sub>F</sub> = 50A, di/dt = 100A/μs	

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.7. Thermal resistance from junction to soldering point (on the exposed drain pad).8. Short duration pulse test used to minimize self-heating effect. Notes:

9. Guaranteed by design. Not subject to production testing.



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DMNH4011SPSQ Document number: DS38693 Rev. 3 - 2



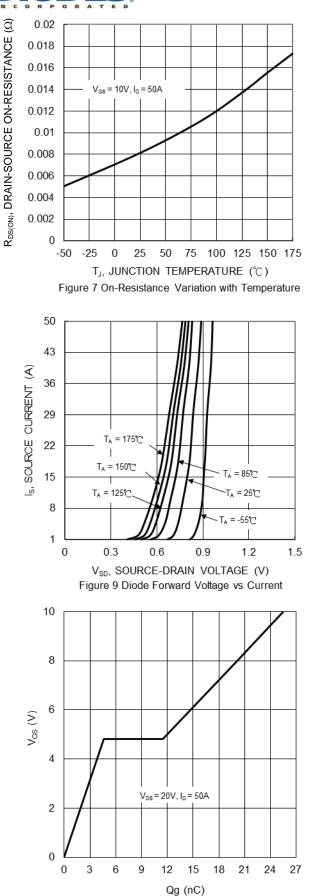
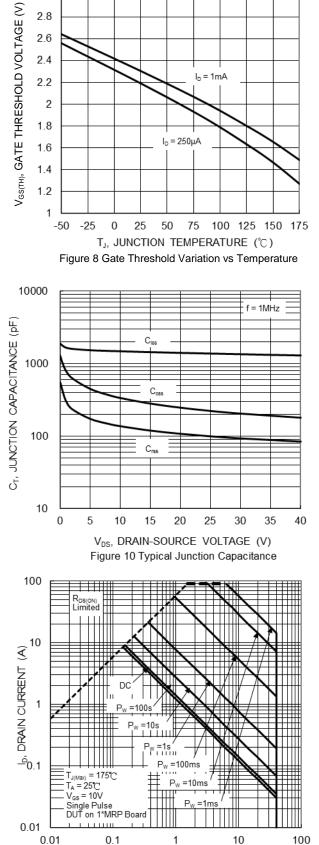


Figure 11 Gate Charge

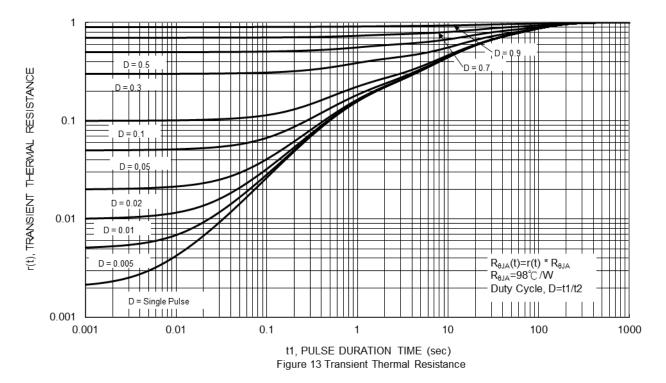


V<sub>DS</sub>, DRAIN-SOURCE VOLTAGE (V) Figure 12 SOA, Safe Operation Area

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DMNH4011SPSQ



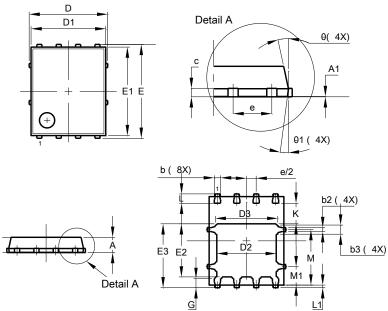




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8

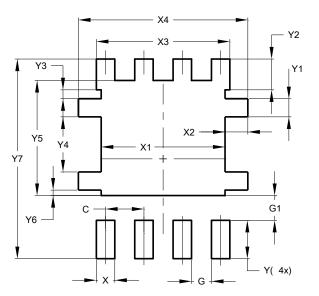


	PowerDI5060-8					
Dim	Min	Тур				
Α	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D		5.15 BSC				
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	4.30	4.10			
Е	6.15 BSC					
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10º	12º	11º			
Θ1	6°	8º	7°			
Al	Dimens	ions in m	าท			

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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